



# NFC TEST REPORT

# No.I21Z70369-IOT04

for

Samsung Electronics Co.,Ltd

**Smart Phone** 

SM-A037G/DSN

FCC ID : ZCASMA037G

with

Hardware Version: REV1.0

Software Version: A037M.001

Issued Date: 2021-07-30

#### Note:

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The report must not be used by the client to claim product certification, approval, or endorsement by NVLAP, NIST, or any agency of the U.S.Government.

**Test Laboratory:** 

#### CTTL-Telecommunication Technology Labs, CAICT

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# **REPORT HISTORY**

Report Number	Revision	Description	Issue Date
I21Z70369-IOT01	Rev.0	1st edition	2021-07-30





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# 1. Test Laboratory

#### 1.1. Introduction & Accreditation

**Telecommunication Technology Labs, CAICT** is an ISO/IEC 17025:2017 accredited test laboratory under NATIONAL VOLUNTARY LABORATORY ACCREDITATION PROGRAM (NVLAP) with lab code 600118-0, and is also an FCC accredited test laboratory (CN5017), and ISED accredited test laboratory (ISED#: 24849). The detail accreditation scope can be found on NVLAP website.

#### 1.2. Testing Location

Location 1: CTTL(huayuan North Road)

Address: No. 52, Huayuan North Road, Haidian District, Beijing, P. R. China 100191

Location 2: CTTL(CuiHu)

Address:

CuiHu Cloud Center No.1 Gaolizhang Road,Wenquan Town,Haidian District,Beijing,China





### 1.3. <u>Testing Environment</u>

Normal Temperature:	15-35°C
Extreme Temperature:	-20/+50°C
Normal Relative Humidity:	20-75%
Normal Air Pressure:	86Kpa-106Kpa

# 1.4. Project data

Testing Start Date:	2021-07-29
Testing End Date:	2021-07-30

#### 1.5. Signature



Zhou Bin (Prepared this test report)

Zhang Qiang (Reviewed this test report)

Zhu Liang (Approved this test report)





# 2. Client Information

## 2.1. Applicant Information

Company Name:	Samsung Electronics Co., Ltd
Address:	19 Chapin Rd., Building D Pine Brook, NJ 07058
Contact:	Jenni Chun
Telephone:	+1-201-937-4203
E-mail:	j1.chun@samsung.com

## 2.2. Manufacturer Information

Company Name:	Samsung Electronics Co., Ltd
Address:	Samsung R5, Maetan dong 129, Samsung ro Youngtong gu, Suwon city 443 742,Korea
Contact:	Sunghoon Cho
Telephone:	+82-10-2722-4159
E-mail:	ggobi.cho@samsung.com





# 3. Equipment Under Test (EUT) and Ancillary Equipment (AE)

### 3.1. About EUT

Smart Phone
SM-A037G/DSN
SAMSUNG
ZCASMA037G
FDD I//V/VIII
GSM 850/900/1800/1900
FDD 1/3/5/7/8/20/28/28a/28b
TDD 38/40/41(2496MHz~2690MHz. Full Band)
-10/+55°C
4V
4.4V
3.6V

### 3.2. Internal Identification of EUT

EUT ID*	IMEI/SNI	HW Version	SW Version	Date of receipt
UT07a	2170369UT07a	REV1.0	A037M.001	2021-07-12
UT08a	2170369UT08a	REV1.0	A037M.001	2021-07-12

\*EUT ID: is used to identify the test sample in the lab internally.

### 3.3. Internal Identification of AE

AE ID*		Description	SN
AE1	Charger1	1	/
AE2	Charger2	1	/
AE3	Charger3	1	/
AE4	Charger4	/	/
AE5	Charger5	1	/
AE6	USB cable	/	/
AE7	Headset1	1	/
AE8	Headset2	/	/
AE9	Battery1	/	/
AE10	Battery2	1	/





AE1	
Model	EP-TA50JWE
Manufacturer	HAEM Co.,Ltd
Length of cable	/
AE2	
Model	EP-TA50JWE
Manufacturer	RFTech Electronics(HuiZhou)Co.,LTD
Length of cable	/
AE3	
Model	EP-TA50UWE
Manufacturer	Dong Yang
Length of cable	/
AE4	
Model	EP-TA50UWE
Manufacturer	HAEM Co.,Ltd
Length of cable	/
AE5	
Model	EP-TA50UWE
Manufacturer	Salcomp
Length of cable	/
AE6	
Model	EP-DR140AWE
Manufacturer	Samsung Electronics Co., Ltd.
Manufacturer Length of cable	
Manufacturer Length of cable AE7	Samsung Electronics Co., Ltd. /
Manufacturer Length of cable AE7 Model	Samsung Electronics Co., Ltd. / EHS61ASFWE
Manufacturer Length of cable AE7 Model Manufacturer	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD
Manufacturer Length of cable AE7 Model Manufacturer Length of cable	Samsung Electronics Co., Ltd. / EHS61ASFWE
Manufacturer Length of cable AE7 Model Manufacturer Length of cable AE8	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD /
Manufacturer Length of cable AE7 Model Manufacturer Length of cable AE8 Model	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD / EHS61ASFWE
Manufacturer Length of cable AE7 Model Manufacturer Length of cable AE8 Model Manufacturer	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD / EHS61ASFWE WATA ELECTRONICS CO.,LTD
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Manufacturer Length of cable AE7 Model Manufacturer Length of cable AE8 Model Manufacturer Length of cable AE9	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD / EHS61ASFWE WATA ELECTRONICS CO.,LTD /
Manufacturer Length of cable AE7 Model Manufacturer Length of cable AE8 Model Manufacturer Length of cable AE9 Type	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD / EHS61ASFWE WATA ELECTRONICS CO.,LTD / Secondary Li-ion Battery
Manufacturer Length of cable AE7 Model Manufacturer Length of cable AE8 Model Manufacturer Length of cable AE9 Type SN	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD / EHS61ASFWE WATA ELECTRONICS CO.,LTD / Secondary Li-ion Battery HQ-50S
Manufacturer Length of cable AE7 Model Manufacturer Length of cable AE8 Model Manufacturer Length of cable AE9 Type SN Manufacturer	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD / EHS61ASFWE WATA ELECTRONICS CO.,LTD / Secondary Li-ion Battery
Manufacturer Length of cable AE7 Model Manufacturer Length of cable AE8 Model Manufacturer Length of cable AE9 Type SN Manufacturer AE10	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD / EHS61ASFWE WATA ELECTRONICS CO.,LTD / Secondary Li-ion Battery HQ-50S SCUD (Fujian) Electronics CO.,LTD
Manufacturer Length of cable AE7 Model Manufacturer Length of cable AE8 Model Manufacturer Length of cable AE9 Type SN Manufacturer AE10 Type	Samsung Electronics Co., Ltd. / EHS61ASFWE DONGGUAN YOUNGBO ELECTRONICS CO.,LTD / EHS61ASFWE WATA ELECTRONICS CO.,LTD / Secondary Li-ion Battery HQ-50S SCUD (Fujian) Electronics CO.,LTD
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### 3.4. EUT Set-ups

#### Table 1: Eut Set-ups

EUT Set-up No.	Combination of EUT and AE	Remarks
Set.NFC01	UT07a + AE1 + AE6 + AE9 + NFC Card	
Set.NFC02	UT07a + AE9 + NFC Card	
Set.NFC03	08a	

The Transmit State of NFC: the NFC function is on. The EUT will transmit the NFC data and command continuously during the test.

The Transmit state without modulation: The EUT will transmit the CW signal at the operating frequency.





## 4. <u>Reference Documents</u>

### 4.1. Documents supplied by applicant

EUT parameters, referring to Annex A for detailed information, are supplied by the client or manufacturer, which are the bases of testing.

#### 4.2. <u>Reference Documents for testing</u>

The following documents listed in this section are referred for testing.

Reference	Title	Version
CFR 47 Part 2	Part 2 — Frequency Allocations and Radio Treaty Matters; General Rules and Regulations.	2019
CFR 47 Part 15	Part 15 — Radio Frequency Devices.	2019
	Subpart C — Intentional Radiators.	
	§ 15.35 Measurement detector functions and bandwidths.	
	§ 15.207 Conducted limits.	
	§ 15.209 Radiated emission limits, general requirements.	
	§ 15.215 Additional provisions to the general radiated emission limitations.	
	§ 15.225 Operation within the band 13.110–14.010 MHz.	
ANSI C63.10	American National Standard of Procedures for Compliance	2013
	Testing of Unlicensed Wireless Devices	





# 5. Test Results

### 5.1. Summary of Test Results

No	Test Cases	Clause in Regulation	Section in This Report	Verdict		
1	Electric Field Strength of Fundamental Emissions	CFR 47 § 15.225(a)	B.1	P(Set. NFC02)		
2	Electric Field Strength of Outside the Allocated Bands	CFR 47 § 15.225(b) CFR 47 § 15.225(c)	D.I	P(Set. NFC02)		
3	Electric Field Radiated	CFR 47 § 15.209	B.2	P(Set. NFC01)		
0	Emissions	CFR 47 § 15.225(d)	B.3	P(Set. NFC01)		
4	Frequency Tolerance	CFR 47 § 15.225(e)	B.4	P(Set. NFC03)		
5	20dB Bandwidth	CFR 47 § 15.215(c)	B.5	P(Set. NFC03)		
6	Conducted Emissions	CFR 47 § 15.207	B.6	P(Set. NFC01)		
The measurement is carried out according to ANSI C63.10. See <b>ANNEX B</b> for details.						

#### Table 2: Summary of Test Results

#### **Test Conditions:**

For this report, all the test cases listed above were tested under normal Temperature, Voltage, humidity and Air Pressure except the Frequency Tolerance test case. The specific conditions of Frequency Tolerance test case are listed in section B.4.3

#### See Table 3 for terms for result verdict:

#### Table 3 Terms for result verdict

Ρ	Pass, The EUT complies with the essential requirements in the standard.
NP	Not Perform, The test was not performed by CTTL
NA	Not Applicable, The test was not applicable
F	Fail, The EUT does not comply with the essential requirements in the standard





### 5.2. Statements

The test cases listed in Section 5.1 of this report for the EUT specified in Section 3 were performed by CTTL according to the reference documents in Section 4.

The EUT meets all applicable requirements of the regulations and standards in Section 4.2





# 6. Test Facilities Utilized

NO.	NAME	TYPE	SERIES NUMBER	PRODUCER	CAL. DUE DATE	CAL. INTERVAL
1.	Spectrum Analyzer	RSA3408A	B010277	Tektronix	2021-10-23	1 Year
2.	Climatic chamber	SH242	93008658	ESPEC	2022-01-22	1 Year
3.	Test Receiver	ESU26	100235	Rohde & Schwarz	2022-02-23	1 Year
4.	BiLog Antenna	VULB9163	9163-483	Schwarzbeck	2021-08-27	1 Year
5.	LISN	ENV216	101200	R&S	2022-05-30	1 Year
6.	Test Receiver	ESCI	100344	R&S	2022-02-23	1 Year
7.	H-field Antenna	HFH2-Z2	829324/007	R&S	2021-12-10	1 Year

#### Table 4: Test Facilities Utilized





# 7. Measurement Uncertainty

#### Table 5: Measurement Uncertainty

Item	Uncertainty
Frequency Tolerance	<i>U</i> =77 Hz, k=2
20dB Bandwidth	<i>U</i> =77 Hz, k=2
Radiated Emissions (<1GHz)	<i>U</i> =4.86 dB, k=2
Radiated Emissions (>1GHz)	<i>U</i> =5.16 dB, k=2
Conducted emission	<i>U</i> = 3.08 dB, k=2



/



# **ANNEX A: EUT parameters**

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# **ANNEX B: Detailed Test Results**

### **B.1. Electric Field Strength of Fundamental and Outside the Allocated bands**

#### B.1.1. Reference

See Clause 4, Clause 5 of ANSI C63.10-2013 generally.

#### **B.1.2. Measurement Methods**

The transmitter carrier output levels (E-Field) from the EUT are measured in a semi-anechoic chamber. The EUT is placed on a non-conductive stand of 80cm high, and at a measurement distance of 3m from the receiving antenna. The center of the receiving loop antenna is 1.0 meter above the ground. The E-field is measured with a shielded loop antenna connected to a measurement receiver. Detected E-field was maximized by rotating the EUT through 360° and adjusting the receiving antenna polarizations. The maximization processes were repeated with the EUT positioned respectively in its three orthogonal axes. The measurements were performed with the peak detector and if required, the quasi-peak detector.

The measurement bandwidth is:

Frequency of Emission (MHz)	RBW/VBW			
12.56-14.56	10/30 kHz			

The E-field measured at 3m is calculated as:

E-field  $(dB\mu V/m) = Rx (dB\mu V) + Cable Loss (dB) + AF@3m (dB/m)$ 





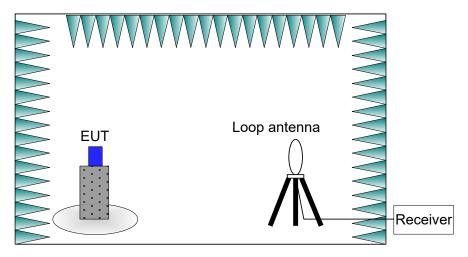


Figure B-1: Measurement Setup

#### B.1.3. EUT Operating Mode and Test Conditions

The measurement of EUT is carried out under the transmit state of NFC(See 3.4).

The EUT is powered by a travel adapter.

All possible configurations were investigated and only the worst case is reported.

During the measurements, the ambient temperature of the electromagnetic anechoic chamber is in the range of 15 ~ 25  $\,^\circ\!\mathrm{C}$ .

#### B.1.4. Limits

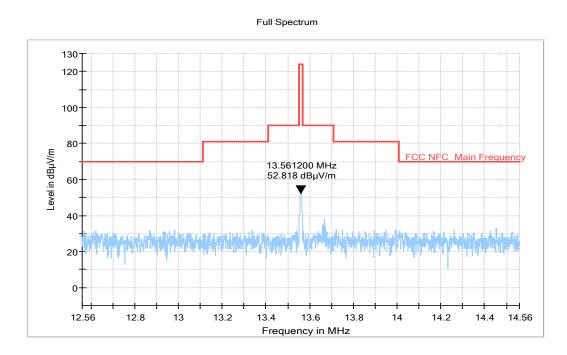
Frequency Range (MHz)	E-field Strength Limit @ 30 m	E-field Strength Limit @ 3 m				
Trequency Range (Miriz)	(µ <b>V/m)</b>	(dBµV/m)				
13.560 ± 0.007	+15,848	124				
13.410 to 13.553	+334	90				
13.567 to 13.710						
13.110 to 13.410	+106	81				
13.710 to 14.010						
Note: Where the limits have been defined at one distance, and a signal level measured at						
another, the limits have been extrapolated using the following formula:						
Extrapolation(dB) = $40\log_{10}$ (Measurement Distance/Specification Distance)						

Table B-2: Limits





Measurement results of normal conditions see Figure B-2 for different set-ups of EUT. The results displayed take into account applicable antenna factors and cable losses.



#### Conclusions: Set.NFC02, PASS.

# Figure B-2: Measurement results for Electric Field Strength of Fundamental and Outside the Allocated bands

### **B.2. Electric Field Radiated Emissions (< 30MHz)**

#### B.2.1. Reference

See Clause 6.4 of ANSI C63.10-2013 specifically.

See Clause 4 and Clause 5 of ANSI C63.10-2013 generally.

#### **B.2.2. Measurement Methods**

The transmitter carrier output levels (E-Field) from the EUT are measured in a semi-anechoic chamber. The EUT is placed on a non-conductive stand of 80cm high, and at a measurement distance of 3m from the receiving antenna. The center of the receiving loop antenna is 1.0 meter above the ground. The E-field is measured with a shielded loop antenna connected to a measurement receiver. Detected E-field was maximized by rotating the EUT through 360° and adjusting the receiving antenna polarizations. The maximization processes were repeated with the EUT positioned respectively in its three orthogonal axes. The measurements were performed with *©Copyright. All rights reserved by CTTL.* 





the peak detector and if required, the quasi-peak detector.

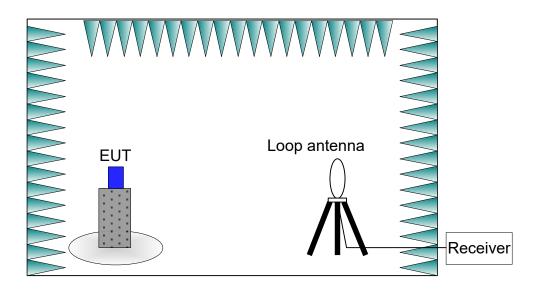
The measurement bandwidth is:

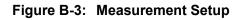
Frequency of Emission (MHz)	RBW/VBW
0.009-0.15	100/300 Hz
0.15-30	10/30 kHz

Table B-3:Measurement bandwidth

The E-field measured at 3m is calculated as:

E-field  $(dB\mu V/m) = Rx (dB\mu V) + Cable Loss (dB) + AF@3m (dB/m)$ 





#### **B.2.3. EUT Operating Mode and Test Conditions**

The measurement of EUT is carried out under the transmit state of NFC(See 3.4).

The EUT is powered by a travel adapter.

All possible configurations were investigated and only the worst case is reported.

During the measurements, the ambient temperature of the electromagnetic anechoic chamber is in the range of  $15 \sim 25$  °C.





#### B.2.4. Limits

#### Table B-4: Limits

	E-field Strength Limit @ 30m	E-field Strength Limit @ 3m				
Frequency Range (MHz)	(mV/m)	(dBµV/m)				
0.009-0.490	2400/F(kHz)	129-94				
0.490-1.705	24000/F(kHz)	74-63				
1.705-30	30	70				
Note: Where the limits have been defined at one distance, and a signal level measured at another, the limits have been extrapolated using the following formula: Extrapolation(dB) = $40\log_{10}$ (Measurement Distance/Specification Distance)						

#### **B.2.5. Measurement Results**

Measurement results of normal conditions see Figure B-4 for different set-ups of EUT. The results displayed take into account applicable antenna factors and cable losses.

#### Conclusions: Set.NFC01, PASS.

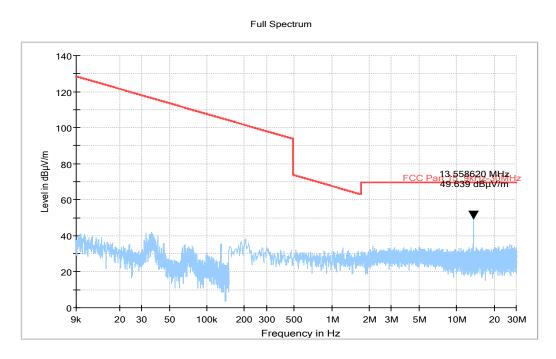


Figure B-4: Measurement results for Electric Field Radiated Emissions (< 30MHz)





### B.3. Electric Field Radiated Emissions (≥30MHz)

#### B.3.1. Reference

See Clause 6.5 of ANSI C63.10-2013 specifically.

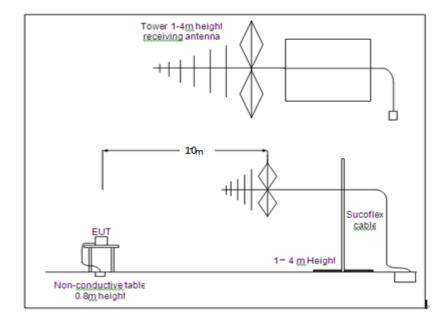
See Clause 4 and Clause 5 of ANSI C63.10-2013 generally.

#### **B.3.2. Measurement Methods**

The electric field radiated emissions from the EUT are measured in a semi-anechoic chamber. The EUT is placed on a non-conductive stand of 80cm high, and at a measurement distance of 10m from the receiving antenna. The receiving antennas connected to a measurement receiver. In order to search for maximum field strength emitted from the EUT, the receiving antenna can be moved between the height of 1.0 m to 4.0 m. Detected E-field was maximized at each frequency by rotating the EUT through 360° and adjusting the receiving antenna positions for both vertical and horizontal antenna polarizations. The maximization processes were repeated with the EUT positioned respectively in its three orthogonal axes. The measurements were performed with the peak detector and if required, the quasi-peak detector.

The measurement bandwidth is:

Frequency of Emission (MHz)	RBW/VBW
30-1000	120kHz



#### Figure B-5: Measurement Setup

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#### Table B-5:Measurement bandwidth





#### **B.3.3. EUT Operating Mode and Test Conditions**

The measurement of EUT is carried out under the transmit state of NFC(See 3.4).

The EUT had been connected to a travel adapter.

All possible configurations were investigated and only the worst case is reported.

During the measurements, the ambient temperature of the electromagnetic anechoic chamber is in the range of  $15 \sim 25$  °C.

#### B.3.4. Limits

Frequency Range (MHz)	E-field Strength Limit @ 3m (mV/m)	E-field Strength Limit @ 3m (dBµV/m)	E-field Strength Limit @ 10m (dBµV/m)
30-88	100	40	30
88-216	150	43.5	33.5
216-960	200	46	36
960-1000	500	54	44

Table B-6: Limits

#### **B.3.5. Measurement Results**

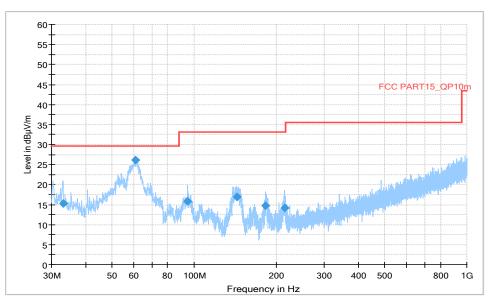
Measurement results of normal conditions see Figure B-6 for different set-ups of EUT. The results displayed take into account applicable antenna factors and cable losses.

Conclusions: Set.NFC01, PASS.





Full Spectrum





# Final\_Result

Frequency	QuasiPeak	Limit	Margin	Meas.	Bandwidth	Height	Pol	Azimuth
(MHz)	(dBµV/m)	(dBµV/m)	(dB)	Time	(kHz)	(cm)		(deg)
				(ms)				
33.104000	15.21	29.50	14.33	1000.0	120.000	187.0	V	30.0
61.040000	26.08	29.50	3.46	1000.0	120.000	235.0	V	210.0
94.796000	15.82	33.10	17.24	1000.0	120.000	339.0	V	30.0
143.490000	16.87	33.10	16.19	1000.0	120.000	100.0	V	-13.0
182.872000	14.68	33.10	18.38	1000.0	120.000	103.0	V	-3.0
214.300000	14.08	33.10	18.98	1000.0	120.000	110.0	V	0.0

### **B.4. Frequency Tolerance**

#### B.4.1. Reference

See Clause 6.8 of ANSI C63.10-2013 specifically.

See Clause 4 and Clause 5 of ANSI C63.10-2013 generally.





#### **B.4.2. Measurement Methods**

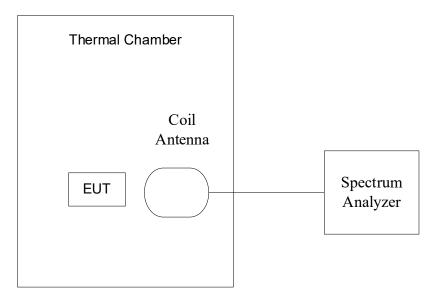


Figure B-7: Measurement Setup

The transmitter output signal was picked up by coil antenna connected to the spectrum analyzer. The center frequency was measured with 30Hz RBW and 1kHz span.

During the test, the EUT was placed in a thermal chamber until thermal balance and lasting appropriate time.

#### B.4.3. EUT Operating Mode and Test Conditions

The measurement of EUT was carried out under the transmit state of without modulation(See 3.4).

EUT had not been connected to a travel adapter. The frequency stability was measured with the different voltage and temperature combinations:

- a) The nominal voltage 4.0V(See 3.1)was used and the temperature was varied from -20 $^{\circ}$ C to +50 $^{\circ}$ C in 10 $^{\circ}$ C increments using an environmental chamber.
- b) The 20 °C was used and the voltages were 3.6V, 4.0V and 4.4V (The extreme low voltage ,the nominal voltage and the extreme high voltage defined in section 3.1).

The details were as following:





Test items	Voltage	Temperature
Frequency		<b>-20</b> ℃
stability with respect		<b>-10</b> ℃
to ambient		
temperature		0°℃
	4.0V	<b>10</b> ℃
		<b>20</b> ℃
		<b>30</b> ℃
		<b>40</b> ℃
		<b>50</b> ℃
Frequency stability	3.6V	
when varying supply voltage	4.0V	<b>20</b> °C
	4.4V	

#### Table B-7: Combinations of Voltage and Temperature

#### B.4.4. Test Layouts

See B.4.2.

#### B.4.5. Limits

The frequency tolerance of the carrier signal shall be maintained within +/- 0.01% of the operating frequency.

#### **B.4.6. Measurement Results**

Measurement results see Table B-8 for different test conditions.

Conclusions: Set.NFC03, PASS.





Temperature	Voltage	Frequency (MHz)			
T omportation o	emperature voltage		2 Min Later	5 Min Later	10 Min Later
-20℃	4.0V	13.560038125	13.560035625	13.560034375	13.560033125
-10℃	4.0V	13.560054375	13.560065625	13.560070625	13.560071875
0°C	4.0V	13.560079375	13.560080125	13.560087375	13.560090215
10°C	4.0V	13.560070625	13.560069375	13.560068125	13.560066875
20°C	4.0V	13.560021875	13.560025625	13.560029375	13.560030625
30℃	4.0V	13.560006875	13.559998125	13.559988750	13.559969125
40°C	4.0V	13.559976875	13.559969375	13.559965625	13.559959375
<b>50℃</b>	4.0V	13.559949375	13.559944375	13.559939375	13.559936875
20°C	3.6V	13.560023125	13.560024375	13.560026875	13.560019375
20°C	4.4 V	13.560026375	13.560028125	13.560029375	13.560030625

Temperature	Voltage	Frequency Error (%)			
· · · · · · · · · · · · · · · · · ·	i enaige	Startup	2 Min Later	5 Min Later	10 Min Later
<b>-20</b> ℃	4.0V	0.000	0.000	0.000	0.000
<b>-10</b> ℃	4.0V	0.000	0.000	0.001	0.001
<b>0</b> °C	4.0V	0.001	0.001	0.001	0.001
<b>10</b> ℃	4.0V	0.001	0.001	0.001	0.000
<b>20</b> ℃	4.0V	0.000	0.000	0.000	0.000
<b>30</b> ℃	4.0V	0.000	0.000	0.000	0.000
<b>40</b> ℃	4.0V	0.000	0.000	0.000	0.000
<b>50</b> ℃	4.0V	0.000	0.000	0.000	0.000
<b>20</b> ℃	3.6V	0.000	0.000	0.000	0.000
<b>20</b> ℃	4.4V	0.000	0.000	0.000	0.000





#### **B.4.7. Measurement Uncertainty**

Measurement uncertainty: U =77 Hz, k=2

#### B.5. 20dB Bandwidth

#### B.5.1. Reference

See Clause 6.9 of ANSI C63.10-2013 specifically.

See Clause 4 and Clause 5 of ANSI C63.10-2013 generally.

#### **B.5.2. Measurement Methods**

The transmitter output signal was picked up by coil antenna connected to the spectrum analyzer. The bandwidth of the center frequency was measured with 140Hz RBW, 420Hz VBW and 14kHz span.

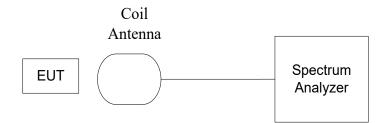


Figure B-8: Measurement Setup

#### **B.5.3. EUT Operating Mode and Test Conditions**

The measurement of EUT was carried out under the transmit state of NFC (See 3.4).

EUT had not been connected to a travel adapter.

During the measurements, the ambient temperature was in the range of  $15 \sim 25$  °C.

#### B.5.4. Test Layouts

See B.5.2.





#### B.5.5. Limits

The 20dB bandwidth shall be less than 80% of the permitted frequency band. For 13.56 MHz NFC, the permitted frequency band is 14kHz, so the limit is 11.2 kHz.

#### **B.5.6. Measurement Results**

Measurement results see Figure B-9.

Conclusions: Set.NFC03, PASS.

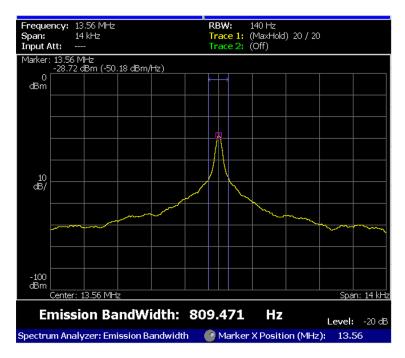


Figure B-9: Measurement results for 20dB Bandwidth

#### **B.5.7. Measurement Uncertainty**

Measurement uncertainty: U =77 Hz, k=2

#### **B.6. Conducted emission**

#### B.6.1. Reference

See Clause 6.2 of ANSI C63.10-2013 specifically.

See Clause 4 and Clause 5 of ANSI C63.10-2013 generally.

#### **B.6.2. Measurement Methods**

The conducted emissions from the AC port of the EUT are measured in a shielding room. The EUT is connected to a Line Impedance Stabilization Network (LISN). An overview sweep with peak detection was performed. The measurements were performed with a quasi-peak detector and if required, an average detector.





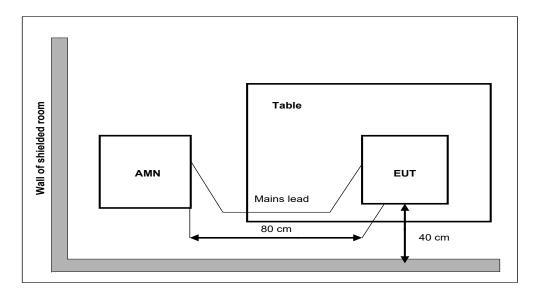
The conducted emission measurements were made with the following detector of the test receiver:

Quasi-Peak / Average Detector.

The measurement bandwidth is:

#### Table B-9: Measurement Bandwidth

Frequency of Emission (MHz)	RBW/VBW		
0.15-30	9kHz		



#### Figure B-10: Measurement Setup

#### **B.6.3. EUT Operating Mode and Test Conditions**

The measurement of EUT is carried out under the transmit state of NFC(See 3.4).

The EUT is powered by a travel adapter.

All possible configurations were investigated and only the worst case is reported.

During the measurements, the ambient temperature is in the range of  $15 \sim 25$  °C.

#### B.6.4. Limits

|--|

Frequency range (MHz)	Quasi-peak Limit (dBµV)	Average Limit (dBμV)
0.15 to 0.5	66 to 56	56 to 46
0.5 to 5	56	46
5 to 30	60	50

#### **B.6.5. Measurement Results**

Measurement results see Figure B-11.





### Conclusions: Set.NFC01, PASS.

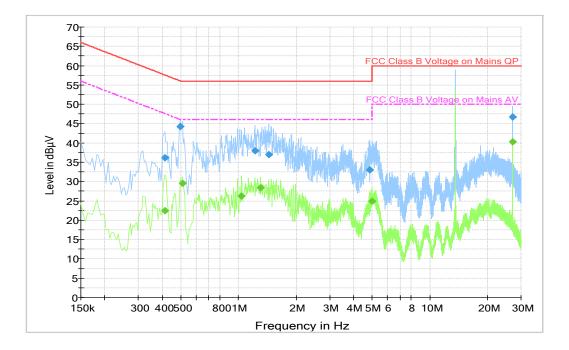


Figure B-11: Measurement results for Conducted Emission

# Final Result 1

Frequency	QuasiPeak	Meas. Time	Bandwidth	Line	Corr.	Margin	Limit
(MHz)	(dBµV)	(ms)	(kHz)		(dB)	(dB)	(dBµV)
0.411000	36.2	1000.0	9.000	L1	19.9	21.4	57.6
0.496500	44.3	1000.0	9.000	L1	19.9	11.8	56.1
1.216500	37.9	1000.0	9.000	L1	19.5	18.1	56.0
1.437000	37.0	1000.0	9.000	L1	19.5	19.0	56.0
4.861500	33.0	1000.0	9.000	L1	19.6	23.0	56.0
27.123000	46.8	1000.0	9.000	L1	20.2	13.2	60.0

### Final Result 2

Frequency	Average	Meas. Time	Bandwidth	Line	Corr.	Margin	Limit
(MHz)	(dBµV)	(ms)	(kHz)		(dB)	(dB)	(dBµV)
0.411000	22.4	1000.0	9.000	L1	19.9	25.2	47.6
0.510000	29.6	1000.0	9.000	L1	19.9	16.4	46.0
1.036500	26.3	1000.0	9.000	L1	19.6	19.7	46.0
1.306500	28.4	1000.0	9.000	L1	19.5	17.6	46.0
4.996500	24.9	1000.0	9.000	L1	19.6	21.1	46.0
27.123000	40.3	1000.0	9.000	L1	20.2	9.7	50.0





# **ANNEX C: Persons involved in this testing**

Test Item	Tester
20dB Bandwidth	Zhou Bin
Frequency Tolerance	Zhou Bin
Electric Field Strength of Fundamental and Outside the Allocated bands	Ding Zai
Electric Field Radiated Emissions (< 30MHz)	Zhang Tianli
Electric Field Radiated Emissions (≥30MHz)	Zhang Tianli
Conducted Emissions	Zhang Tianli

#### Table C-1: Persons involved





# **ANNEX D: Accreditation Certificate**



\*\*\*END OF REPORT\*\*\*